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View Online at https://aerobasegroup.com/nsn/5961-00-419-4533
Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current
Power Rating Per Characteristic:
1.2 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Test Data Document:
00752-313314 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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